

BDV65B-S Information



For Reference Only

Part Number BDV65B-S **Manufacturer** Bourns Inc.

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN DARL 100V 12A

Package TO-218-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BDV65B-S Specifications

Manufacturer Part Number	BDV65B-S
Manufacturer	Bourns Inc.
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-218-3
Series	-
Transistor Type	NPN - Darlington
Current - Collector (Ic) (Max)	12A
Voltage - Collector Emitter Breakdown (Max)	100V
Vce Saturation (Max) @ Ib, Ic	2V @ 20mA, 5A
Current - Collector Cutoff (Max)	2mA
DC Current Gain (hFE) (Min) @ Ic, Vce	1000 @ 5A, 4V
Power - Max	3.5W
Frequency - Transition	-
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-218-3
Supplier Device Package	SOT-93
	Report errors?

BDV65B-S Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BDV65B-S Payment Methods



















BDV65B-S Shipping Methods













If you have any question about BDV65B-S, please do not hesitate to contact us!

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